NSN 5961-00-070-7887

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with all other terminals short-circuited to source and 30.0

to source

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View Online at https://aerobasegroup.com/nsn/5961-00-070-7887
Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-72
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.0 drain to source voltage and 30.0 breakdown voltage, drain-to-source, with all
breakdown voltage, gate-to-source, with all other terminals short-circuited to sourc
Current Rating Per Characteristic:
5.00 milliamperes drain current and 100.00 microamperes gate current
Power Rating Per Characteristic:
225.0 milliwatts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
4 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0